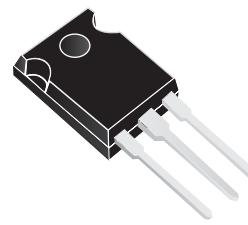
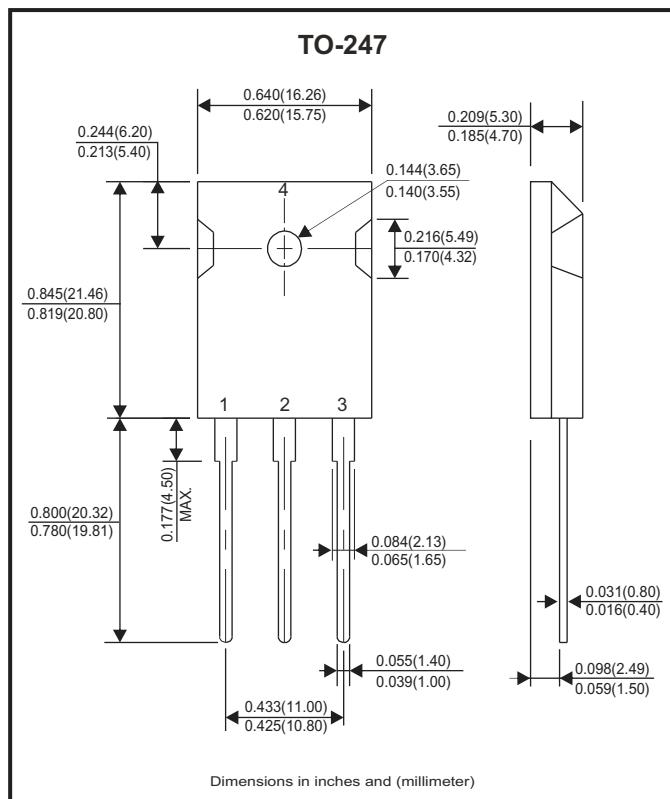
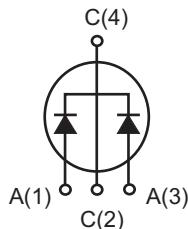


**CDBGBSC201200-G****Reverse Voltage: 1200V****Forward Current: 20A****RoHS Device****Features**

- Rated to 1200 at 20 Amps
- Short recovery time
- High speed switching possible
- High frequency operation.
- High temperature operation.
- Temperature independent switching behaviour.
- Positive temperature coefficient on VF

**Circuit diagram****Maximum Ratings** (at  $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Repetitive peak reverse voltage	$T_J = 25^\circ\text{C}$	$V_{RRM}$	1200	V
Surge peak reverse voltage	$T_J = 25^\circ\text{C}$	$V_{RSM}$	1200	V
DC blocking voltage	$T_J = 25^\circ\text{C}$	$V_{DC}$	1200	V
Continuous forward current	$T_c = 25^\circ\text{C}$ (Per leg) $T_c = 135^\circ\text{C}$ (Per leg) $T_c = 155^\circ\text{C}$ (Per leg)	$I_F$	25.9 12.5 10	A
Repetitive peak forward surge current	$T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave, $D = 0.3$ (Per leg)	$I_{FRM}$	50	A
Non-repetitive peak forward surge current	$T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave (Per leg)	$I_{FSM}$	100	A
Power dissipation	$T_c = 25^\circ\text{C}$ (Per leg)	$P_{TOT}$	141.5	W
	$T_c = 110^\circ\text{C}$ (Per leg)		62	
Typical thermal resistance from junction to case	Per leg	$R_{\theta JC}$	1.06	°C/W
	Per diode	$R_{\theta JC}$	0.27	
Maximum case temperature		$T_c$	135	°C
Operating junction temperature range		$T_J$	-55 ~ +175	°C
Storage temperature range		$T_{STG}$	-55 ~ +175	°C

Company reserves the right to improve product design, functions and reliability without notice.

REV:

## Electrical Characteristics (at $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 10\text{A}, T_j = 25^\circ\text{C}$	$V_F$		1.63	1.8	V
	$I_F = 10\text{A}, T_j = 175^\circ\text{C}$			2.55	3	
Reverse current	$V_R = 1200\text{V}, T_j = 25^\circ\text{C}$	$I_R$		50	100	$\mu\text{A}$
	$V_R = 1200\text{V}, T_j = 175^\circ\text{C}$			100	200	
Total capacitive charge	$V_R = 800\text{V}, T_j = 150^\circ\text{C}$ $Q_C = \int_0^{V_R} C(V) dV$	$Q_C$		69	-	nC
Total capacitance	$V_R = 0\text{V}, T_j = 25^\circ\text{C}, f = 1\text{MHz}$	$C$		770	790	$\text{pF}$
	$V_R = 400\text{V}, T_j = 25^\circ\text{C}, f = 1\text{MHz}$			52	54	
	$V_R = 800\text{V}, T_j = 25^\circ\text{C}, f = 1\text{MHz}$			50	51	

## RATING AND CHARACTERISTIC CURVES (CDBGBC201200-G)

Fig.1 - Forward IV Characteristics as a Function of  $T_J$ :

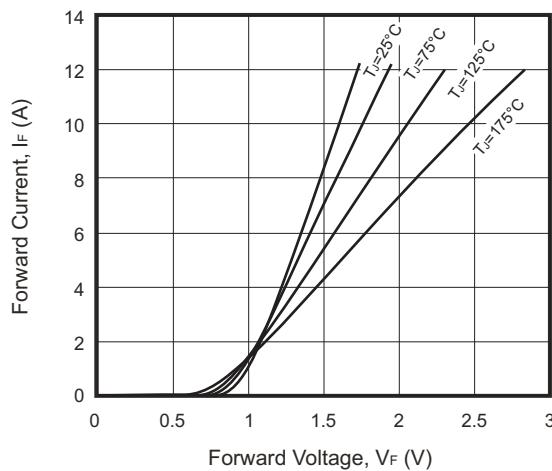


Fig.2 - Reverse IV Characteristics as a Function of  $T_J$ :

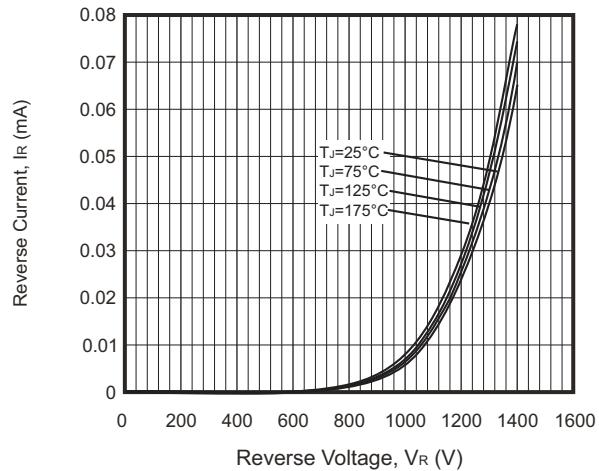


Fig.3 - Current Derating

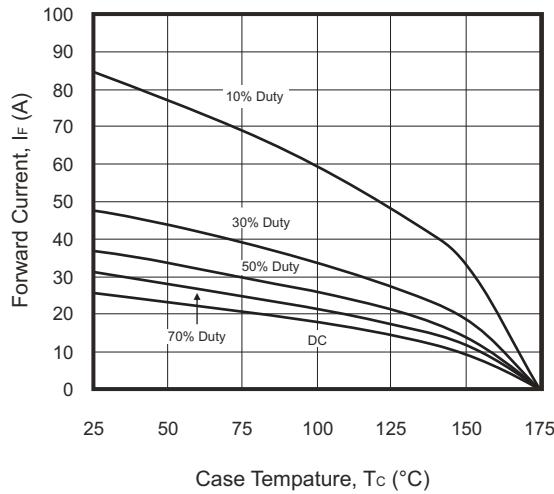


Fig.4 - Capacitance VS. Reverse Voltage

